Samsung M3 Processor

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Samsung M3 Processor

• ISA - ARM v8.0, 64-bit/32-bit compliant.
• Leveraged database from M1 starting RTL back in 2015
• Goal:
  — Incremental improvement
  — Much improved design: Wider, Deeper, Faster
• Challenge:
  — Smartphone launch cycle is relentless: must hit schedule
• Q1 2018:
  — Productized 2.7Ghz in Samsung 10nm LPP
  — Established new standard of performance for Android smartphones
Samsung M3 Overview

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Diagram showing the architecture of Samsung M3.
Samsung M3 Front End

M3 Branch Prediction:
• 128-entry microBTB (2x)
• 4K-entry mainBTB: improved branch-taken latency
• 16K capacity L2 BTB (2x capacity, 2x bandwidth)
• Conditional predictor improvements including more weights for Neural Net
• Improvements to the Indirect Predictor
=> Net of above led to average MPKI reduction ~15%

M3 Instruction Fetch:
• 64KB/4-way
• Read up to 48 Bytes / cycle (2x fetch width)
• Decoupling Instruction Queue (nearly 2x deeper)
• 512 entry ITLB (2x)

MPKI comparison across ~4800 traces sorted by M3
Samsung M3 Middle Machine

• Wider:
  • Decode up to 6 inst/cycle (1.5x wider than prior)
    - Several fusion idioms supported
  • Rename, Dispatch, Retire: up to 6 uops/cycle (1.5x wider than prior)
  • Up to 9 integer ops issued/cycle (versus 7 in prior)
    • 4th ALU including a 2nd integer multiplier
    • 2nd Load AGU – part of doubling load bandwidth

• Deeper:
  • 228-entry ROB (>2x deeper program window than prior)
  • 126-entry distributed integer scheduler (>2x deeper than M1)

• Faster Instructions:
  • Additional 1-cycle latency ops
  • Some ops optimized to 0-cycle latency
  • Integer Divider now radix 16 (4 bits/cycle) versus prior radix 4 (2 bits/cycle)
Samsung M3 FPU

- **Wider:**
  - 3rd dispatch and issue ports (1.5x)
  - 3x 128b FMAC/FADD (versus M1 1 128b FMAC + 1 128b FADD)
    => 2x maximum FLOPS
  - 2nd 128b Load port
    => critical to feed the FP “beast”

- **Deeper Out-of-Order**
  - 62-entry FP scheduler (nearly 2x versus prior)
  - 192-entry FP PRF (2x versus prior)

- **Faster Instructions:**
  - FMAC: 4-cycle MAC (was 5)
    - 3-cycle Mul (was 4)
  - FADD: 2-cycle (was 4)
  - FDIV: radix64 (was radix4)
    => 6 bits/cycle versus 2
Samsung M3 Load/Store Unit

- **Bandwidths:**
  - 2-Load/cycle (2x read bandwidth vs. prior)
  - 1-Store/cycle
  - Additional Stream/Copy Optimizations
- **Depth:**
  - Larger schedulers
  - Doubled Store Buffer
  - 12 outstanding misses (8 prior)
- **Latencies:**
  - 64KB/8-way D$ for 4 cycle (integer) - twice the former capacity @ same latency
  - Enhanced and Hybridized Prefetcher
  - TLBs
    - New mid-level 512-entry DTLB
    - Enhanced unified L2TLB – 4K entry (vs 1K)
Deeper and Wider were not free. Versus M1:
1: A second stage of dispatch was added
2: A second stage for PRF read was added
Samsung M3 Cache Hierarchy

M1/M2: 16B/cycle/CPU
shared L2 (inclusive of D$)
  • 2MB, 16-way, 22c
L2/BIU: 56 outstanding transactions

M3: 32B/cycle/CPU (2x bandwidth)
Private L2 (inclusive of D$)
  • 512KB, 8w, 12c
SL3 (exclusive of L2$)
  • 4MB, 16/way, ~37c typical (NUCA)
  • Slice design - 1MB per slice
  => Goal: configurability
BIU – 80 outstanding transactions
Performance Infrastructure

Dedicated performance team ran comprehensive simulations to guide tradeoffs across the design.

~4800 traces including:
Spec (2K/2K6, Int/FP), GBv4, Antutu, Octane, Sunspider, Bbench, browsermark, and more.

Correlation team ran hundreds of execution snippets across RTL and model to find design mistakes and improve prediction accuracy. Emulator team provided additional support by running long term simulations – found branch predictor “leak” this way.

Simulated IPC comparison across ~4800 unweighted traces; Both M2 and M3 sorted here; IPC will vary across applications/benchmarks
Samsung 10LPP
M3 CPU: 2.52 mm²
M3 pL2: 0.98 mm²
Samsung 10LPP M3 4P Cluster: 20.9 mm²

L3 slices: design once, replicate 4 times
Silicon Performance Comparison – GB4 single relative to M2

New level of performance established for the Android eco-system
Perf/Power Efficiency superior for M3 at iso-frequency with M2;
Efficiency in 1P frequency boost mode in-range
New CPU every year

Team now on strong annual cadence: expect more improvements every year

Samsung M3

- Next Gen Planning Started - Q2 2014
- RTL Start – Q1 2015
- Fork features for incremental M2 - Q3 2015
- Replan for a bigger M3 push - Q1 2016
- Tapeout EVT0 – Q1 2017
- Product Launch: Q1 2018

M1 – 2016
M2 – 2017
M3 – 2018
Conclusion

• Samsung’s 3rd generation design for ARMv8
• On schedule production launch
• Wider, Deeper, Faster ...
  Best CPU for Android smartphones
• More designs to come